
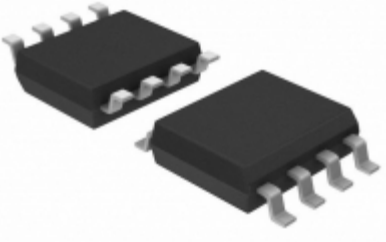
	<h2>SI4288DY-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI4288DY-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 40V 9.2A 8SO</p> <p>Datenblätter:  SI4288DY-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 814442 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI4288DY-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 40V 9.2A 8SO
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	814442 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	3.1W
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	40V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9.2A
Rds On (Max) @ Id, Vgs	20 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	580pF @ 20V
Verpackung	Tape & Reel (TR)



















































SI4288DY-T1-GE3 ist neu im Original, Suche SI4288DY-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4288DY-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4288DY-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4300-E-BM Energy Micro (Silicon Labs) IC POWER AMP DUAL-BAND 20C-LGA</p>	 <p>SI4286DY-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 40V 7A 8SO</p>	 <p>SI4300-BM SILICON SI4300-BM SILICON</p>	 <p>SI4288DY VISHAY SI4288DY VISHAY</p>
 <p>SI43-1K5-R DELTA DELTA SMD</p>	 <p>SI4300-E-BMR SILICON SI4300-E-BMR SILICON</p>	 <p>SI4300-D-BMR SILICON SI4300-D-BMR SILICON</p>	 <p>SI4288DY-T1-E3 VISHAY SI4288DY-T1-E3 VISHAY</p>

heiße Teile

Mehr

 SI4214DDY-T1-GE3	 SI4214DDY-T1-GE3	 SI4214DY-T1-E3	 SI4214DY-T1-GE3	 SI4214DY-T1-GE3
 SI4220-GM	 SI4226DY	 SI4226DY-T1-E3	 SI4226DY-T1-E3	 SI4226DY-T1-GE3
 SI4226DY-T1-GE3	 SI4228DY	 SI4228DY-T1-E3	 SI4228DY-T1-E3	 SI4228DY-T1-GE3
 SI4228DY-T1-GE3	 SI4232DY.	 SI4276DY-T1-E3	 SI4276DY-T1-E3	 SI4282DVP
 SI4286DY	 SI4286DY-T1-GE3	 SI4286DY-T1-GE3	 SI4288DY	 SI4288DY-T1-GE3
 SI4300-BM	 SI4300-E-BM	 SI4300DY-T1-E3	 SI4308DY-T1	 SI4308DY-T1-E3
 SI4311-B21-GMR	 SI4320-J1-FTR	 SI4320DY	 SI4320DY-T1-E3	 SI4320DY-T1-E3
 SI4322-A0-FT	 SI4322-A0-FTR	 SI4322DY-T1-E3	 SI4322DY-T1-E3	 SI4324DY
 SI4324DY-T1-E3	 SI4324DY-T1-E3	 SI4326DY-T1-E3	 SI4330BDY-T1-GE3	 SI4330DY-T1
 SI4330DY-T1-E3	 SI4330DY-T1-E3	 SI4330DY-T1-E3.	 SI4334DY-T1-E3	 SI4336DY

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